

ZXTN5551Z 160V, SOT89, NPN high voltage transistor

Summary

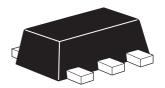
BV_{CEO} > 160V

 $BV_{EBO} > 6V$

 $I_{C(cont)} = 600 mA$

 $P_{D} = 1.2W$

Complementary part number ZXTP5401Z

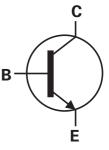


Description

A high voltage NPN transistor in a small outline surface mount package

Features

- 160V rating
- SOT89 package

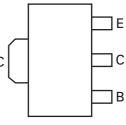


Applications

· High voltage amplification

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN5551ZTA	7	12	1000



Pinout - top view

Device marking

N51

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	180	V
Collector-emitter voltage	V _{CEO}	160	V
Emitter-base voltage	V _{EBO}	6	V
Continuous collector current ^(a)	I _C	600	mA
Power dissipation at T _A =25°C ^(a)	P _D	1.2	W
Linear derating factor		9.6	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

Thermal resistance

Parameter	Symbol	Value	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	104	°C/W

NOTES:

(a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Electrical characteristics (at $T_{amb} = 25$ °C unless otherwise stated).

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	180	270		V	I _C = 100μA
Collector-emitter breakdown voltage (base open)	BV _{CEO}	160	200		V	I _C = 1mA ^(*)
Emitter-base breakdown voltage	BV _{EBO}	6	7.85		V	I _E = 10μA
Collector cut-off current	I _{CBO}		<1	50	nA	V _{CB} = 120V
				50	μΑ	$V_{CB} = 120V, T_{amb} = 100^{\circ}C$
Collector-emitter	V _{CE(sat)}		65	150	mV	I _C = 10mA, I _B = 1mA ^(*)
saturation voltage			115	200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}^{(*)}$
Base-emitter saturation	V _{BE(sat)}		760	1000	mV	I _C = 10mA, I _B = 1mA ^(*)
voltage			840	1200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}^{(*)}$
Static forward current	h _{FE}	80	130			$I_C = 1mA, V_{CE} = 5V^{(*)}$
transfer ratio		80	145	250		$I_C = 10 \text{mA}, V_{CE} = 5V^{(*)}$
		30	65			$I_C = 50 \text{mA}, V_{CE} = 5V^{(*)}$
Transition frequency	f _T		130		MHz	I _C = 10mA, V _{CE} = 10V f = 100MHz
Output capacitance	C _{OBO}			6	pF	V _{CB} = 10V, f = 1MHz ^(*)
Small signal	h _{FE}	50		260		I _C = 10mA, V _{CE} = 10V, f=1kHz ^(†)
Delay time	t _(d)		95		ns	V _{CC} = 10V. I _C = 10mA,
Rise time	t _(r)		64		ns	$I_{B1} = I_{B2} = 1mA.$
Storage time	t _(s)		1256		ns	
Fall time	t _(f)		140		ns	

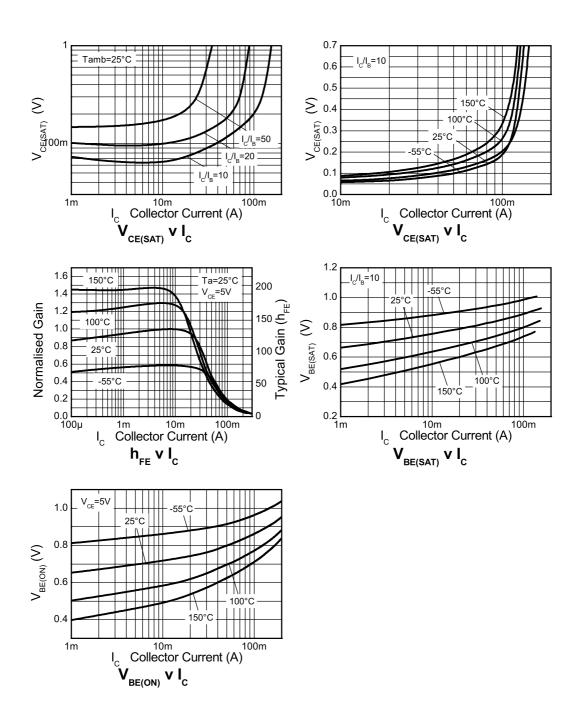
NOTES:

^(*) Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$.

^(†) Periodic sample test only



Typical characteristics



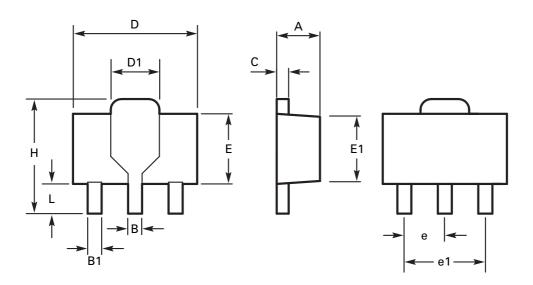
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Package outline - SOT89



DIM	Millin	neters	Inc	hes	DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
Α	1.40	1.60	0.550	0.630	Е	2.29	2.60	0.090	0.102
В	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090
B1	0.36	0.48	0.014	0.019	е	1.50 BSC		0.059 BSC	
С	0.35	0.44	0.014	0.017	e1	3.00 BSC		0.118	BSC
D	4.40	4.60	0.173	0.181	Н	3.94	4.25	0.155	0.167
D1	1.52	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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